



40V 150°C N-CHANNEL ENHANCEMENT MODE MOSFET PowerDI3333-8

Product Summary

BV _{DSS}	R _{DS(ON)} Max	I _D Max T _C = +25°C
40V	$7.5 \text{m}\Omega$ @ $V_{GS} = 10 \text{V}$	49.1A

Description and Applications

This new generation MOSFET is designed to minimize the on-state resistance (RDS(ON)) yet maintain superior switching performance, making it ideal for high-efficiency power-management applications.

- Motor controls
- Power-management functions
- DC-DC converters

Features and Benefits

- Excellent Q_{GD} × R_{DS(ON)} Product (FOM)
- Low Rds(ON) Ensures On-State Losses are Minimized
- 100% Unclamped Inductive Switching, Test in Production Ensures More Reliable and Robust End Application
- Wettable Flank for Improved Optical Inspection
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- This part is qualified to JEDEC standards (as references in AEC-Q) for High Reliability.

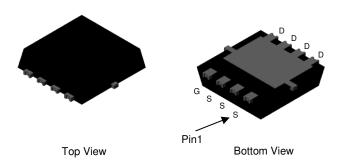
https://www.diodes.com/quality/product-definitions/

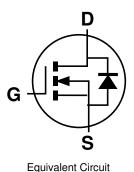
An automotive-compliant part is available under separate datasheet (<u>DMT47M2SFVWQ</u>)

Mechanical Data

- Package: PowerDI[®]3333-8
- Package Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Finish Matte Tin Annealed over Copper Leadframe;
 Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.025 grams (Approximate)

PowerDI3333-8 (SWP) (Type UX)





Ordering Information (Note 4)

i					
	Part Number	Packago	Packing		
	Part Number	Package	Qty.	Carrier	
	DMT47M2SFVW-7	PowerDI3333-8 (SWP) (Type UX)	2,000	Tape & Reel	
	DMT47M2SFVW-13	PowerDI3333-8 (SWP) (Type UX)	3.000	Tape & Reel	

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information





Characteristic	Symbol	Value	Unit	
Drain-Source Voltage	V_{DSS}	40	V	
Gate-Source Voltage		V _{GSS}	±20	V
Continuous Drain Current (Note 6), V _{GS} = 10V	T _C = +25°C T _C = +70°C	Ι _D	49.1 39.2	А
Continuous Drain Current (Note 5), $V_{GS} = 10V$ $T_A = +25^{\circ}C$ $T_A = +70^{\circ}C$		lσ	15.4 12.3	А
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)	I _{DM}	196	Α	
Maximum Continuous Body Diode Forward Current (Note 6)	ls	30.8	Α	
Pulsed Body Diode Forward Current (10µs Pulse, Duty Cycle =	Ism	196	Α	
Avalanche Current, L = 0.1mH	las	24.7	A	
Avalanche Energy, L = 0.1mH	E _{AS}	30.5	mJ	

Thermal Characteristics

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 5)	T _A = +25°C	PD	2.67	W
Thermal Resistance, Junction to Ambient (Note 5)		RθJA	46.5	°C/W
Total Power Dissipation (Note 6) $T_C = +25^{\circ}C$		PD	27.1	W
Thermal Resistance, Junction to Case (Note 6)		$R_{ heta JC}$	4.61	°C/W
Operating and Storage Temperature Range		TJ, TSTG	-55 to +150	°C

Electrical Characteristics (@TA = +25°C, unless otherwise specified.)

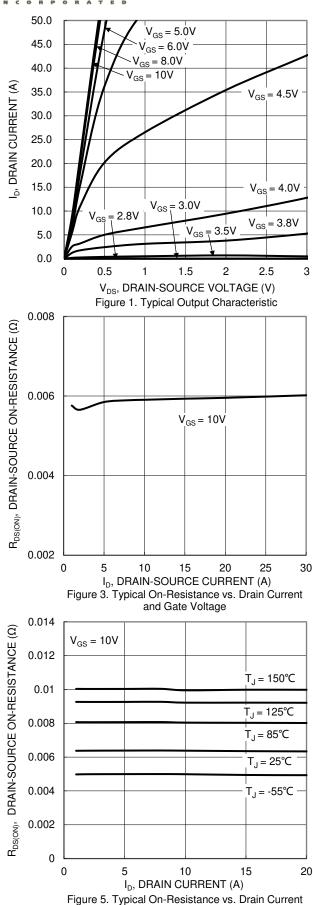
Characteristic		Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)							
Drain-Source Breakdown Voltage	BV _{DSS}	40	_	_	V	$V_{GS} = 0V, I_{D} = 250\mu A$	
Zero Gate Voltage Drain Current	IDSS			1	μΑ	$V_{DS} = 32V$, $V_{GS} = 0V$	
Gate-Source Leakage	Igss			±100	nA	$V_{GS} = \pm 20V$, $V_{DS} = 0V$	
ON CHARACTERISTICS (Note 7)							
Gate Threshold Voltage	V _{GS(TH)}	2	2.5	4	٧	$V_{DS} = V_{GS}$, $I_D = 250\mu A$	
Static Drain-Source On-Resistance	RDS(ON)		5.9	7.5	mΩ	$V_{GS} = 10V, I_D = 20A$	
Diode Forward Voltage	V _{SD}		0.88	1.2	V	$V_{GS} = 0V, I_{S} = 20A$	
DYNAMIC CHARACTERISTICS (Note 8)							
Input Capacitance	Ciss		897	_	pF	V _{DS} = 20V, V _{GS} = 0V, f = 1MHz	
Output Capacitance	Coss	_	530	_			
Reverse Transfer Capacitance	Crss		12.4	_			
Gate Resistance	Rg		2.07	_	Ω	$V_{DS} = 0V$, $V_{GS} = 0V$, $f = 1MHz$	
Total Gate Charge	Qg		12.1	_			
Gate-Source Charge	Qgs		2.0	_	nC	$V_{DS} = 20V, I_{D} = 20A, V_{GS} = 10V$	
Gate-Drain Charge	Q_{gd}		1.9	_			
Turn-On Delay Time	td(ON)		5.36	_		$\begin{split} V_{DD} &= 20 V, V_{GS} = 10 V, \\ R_G &= 3 \Omega, I_D = 20 A \end{split}$	
Turn-On Rise Time	t _R		4.54	_	ns		
Turn-Off Delay Time	tD(OFF)	_	12.1	_	115		
Turn-Off Fall Time	tF		5.59	_			
Body Diode Reverse Recovery Time	trr		39.1	_	ns	I- 204 di/dt 1004/vs	
Body Diode Reverse Recovery Charge	Qrr	_	53.3	_	nC	$I_F = 20A$, di/dt = 100A/ μ s	

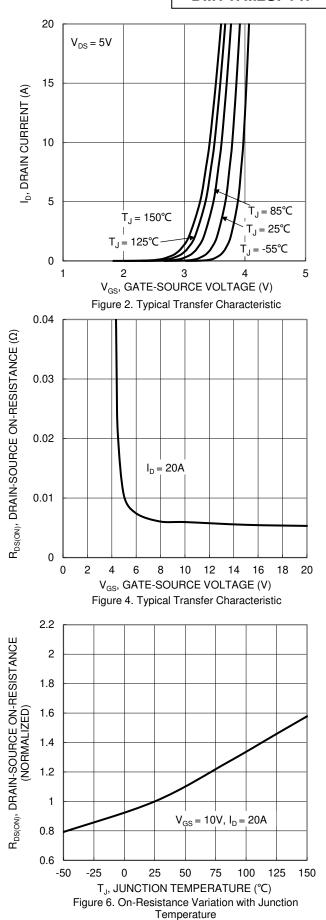
5. Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1inch square copper plate. Notes:

- 6. Thermal resistance from junction to soldering point (on the exposed drain pad).7. Short duration pulse test used to minimize self-heating effect.8. Guaranteed by design. Not subject to production testing.

DMT47M2SFVW







and Junction Temperature



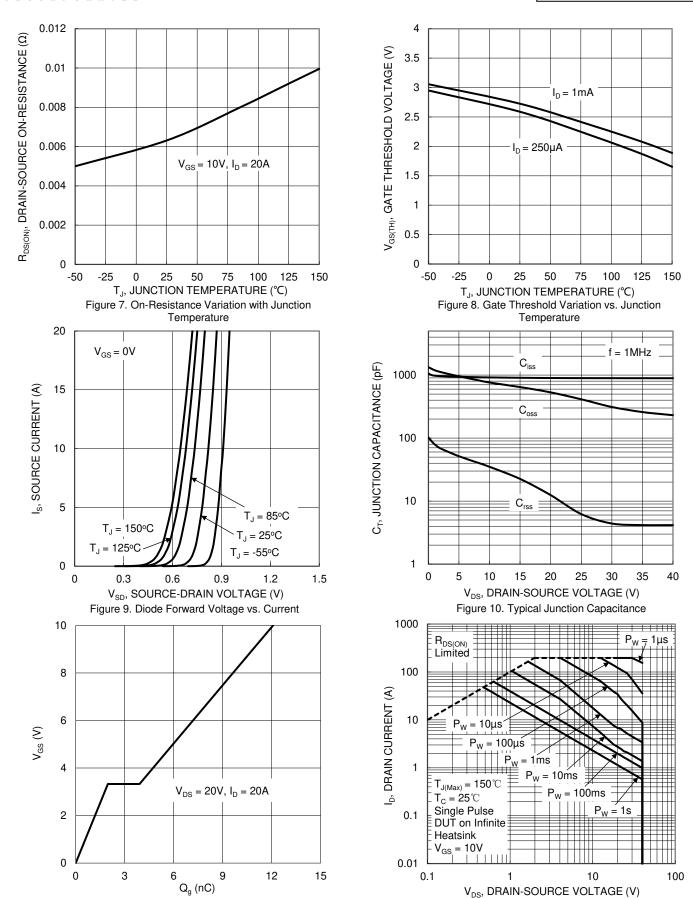


Figure 11. Gate Charge

Figure 12. SOA, Safe Operation Area



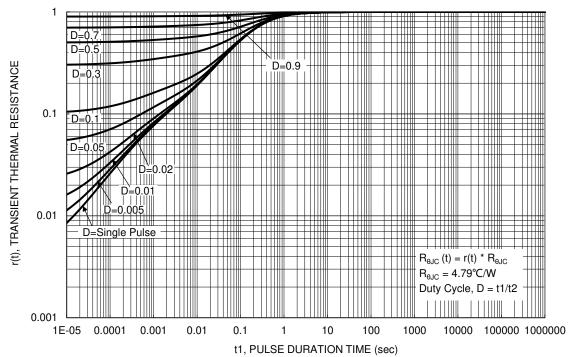


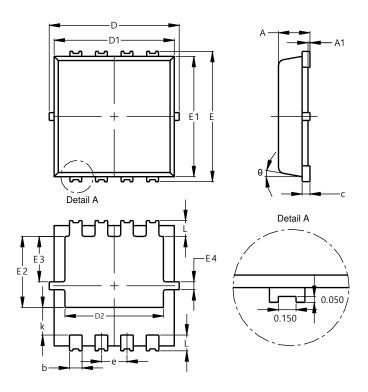
Figure 13. Transient Thermal Resistance



Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI3333-8 (SWP) (Type UX)

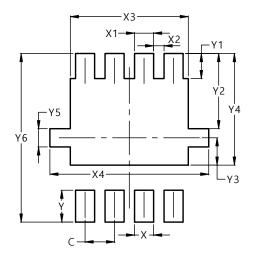


PowerDI3333-8 (SWP)					
(Type UX)					
Dim	Min	Max	Тур		
Α	0.75	0.85	0.80		
A 1	0.00	0.05			
b	0.25	0.40	0.32		
С	0.10	0.25	0.15		
D	3.20	3.40	3.30		
D1	2.95	3.15	3.05		
D2	2.30	2.70	2.50		
Е	3.20	3.40	3.30		
E1	2.95	3.15	3.05		
E2	1.60	2.00	1.80		
E3	0.95	1.35	1.15		
E4	0.10	0.30	0.20		
е			0.65		
k	0.50	0.90	0.70		
L	0.30	0.50	0.40		
θ	0°	12°	10°		
All Dimensions in mm					

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI3333-8 (SWP) (Type UX)



Dimensions	Value (in mm)		
С	0.650		
X	0.420		
X1	0.420		
X2	0.230		
Х3	2.600		
X4	3.500		
Υ	0.700		
Y1	0.550		
Y2	1.650		
Y3	0.600		
Y4	2.450		
Y5	0.400		
Y6	3.700		



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